

# 1.5V Drive Pch MOSFET

## RZR020P01

#### ●Structure

Silicon P-channel MOSFET

#### Features

- 1) Low on-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small and Surface Mount Package (TSMT3).
- 4) Low voltage drive (1.5V).

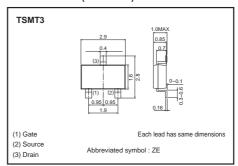
# Applications

Switching

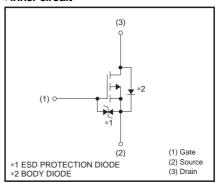
#### Packaging specifications

	Package	Taping
Type	Code	TL
	Basic ordering unit (pieces)	3000
RZR020P01	0	

#### ●Dimensions (Unit: mm)



#### •Inner circuit



#### ● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Drain-source voltage		V <sub>DSS</sub>	-12	V	
Gate-source voltage		V <sub>GSS</sub>	±10	V	
Drain current	Continuous	lσ	±2	A	
	Pulsed	I <sub>DP</sub> *1	±6	А	
Source current	Continuous	Is	-0.8	А	
(Body diode)	Pulsed	I <sub>SP</sub> *1	-6	А	
Total power dissipation		P <sub>D</sub> *2	1.0	W	
Channel temperature		Tch	150	°C	
Range of storage temperature		Tstg	-55 to +150	°C	

#### Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth (ch-a) *	125	°C/W

<sup>\*</sup> When mounted on a ceramic board.

<sup>\*1</sup> Pw≤10µs, Duty cycle≤1% \*2 When mounted on a ceramic board.

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## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	_	-	±10	μΑ	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	$V_{(BR)\;DSS}$	-12	_	_	V	I <sub>D</sub> = -1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	IDSS	_	-	-1	μΑ	V <sub>DS</sub> = -12V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS (th)</sub>	-0.3	-	-1.0	V	$V_{DS}$ = -6V, $I_{D}$ = -1mA
	R <sub>DS</sub> (on)*	_	75	105	mΩ	I <sub>D</sub> = -2A, V <sub>G</sub> S= -4.5V
Static drain-source on-state		_	105	145	mΩ	I <sub>D</sub> = -1A, V <sub>G</sub> s= -2.5V
resistance		_	150	225	mΩ	I <sub>D</sub> = -1A, V <sub>G</sub> s= -1.8V
		_	200	400	mΩ	I <sub>D</sub> = -0.4A, V <sub>G</sub> S= -1.5V
Forward transfer admittance	Y <sub>fs</sub> *	2	-	_	S	V <sub>DS</sub> = -6V, I <sub>D</sub> = -2A
Input capacitance	Ciss	_	770	_	pF	V <sub>DS</sub> = -6V
Output capacitance	Coss	_	75	_	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	Crss	_	60	_	pF	f=1MHz
Turn-on delay time	t <sub>d (on)</sub> *	_	10	_	ns	V <sub>DD</sub> ≒ −6V
Rise time	tr *	-	17	-	ns	ID= -1A
Turn-off delay time	td (off) *	_	65	_	ns	$V_{GS} = -4.5V$ $R_L = 6\Omega$
Fall time	t <sub>f</sub> *	_	35	_	ns	R <sub>G</sub> =10Ω
Total gate charge	Qg *	_	6.5	_	nC	V <sub>DD</sub> ≒-6V, I <sub>D</sub> =-2A
Gate-source charge	Q <sub>gs</sub> *	_	1.3	_	nC	V <sub>GS</sub> = -4.5V
Gate-drain charge	Q <sub>gd</sub> *	1	0.8	_	nC	$R \vdash 3\Omega, R_G=10\Omega$

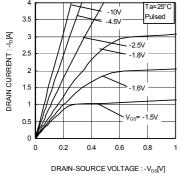
<sup>\*</sup>Pulsed

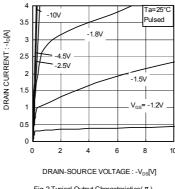
# ●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp *	_	_	-1.2	V	Is= -2A, Vgs=0V

<sup>\*</sup> Pulsed

#### •Electrical characteristics curves





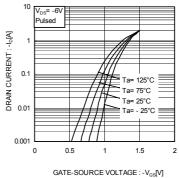
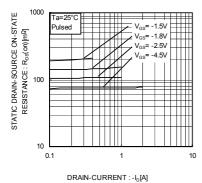
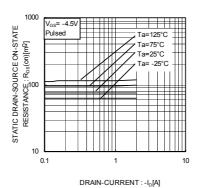


Fig.1 Typical Output Characteristics( I )

Fig.2 Typical Output Characteristics(  $\underline{\mathbb{I}}$  )

Fig.3 Typical Transfer Characteristics





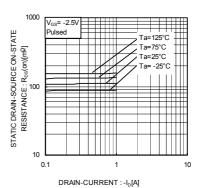
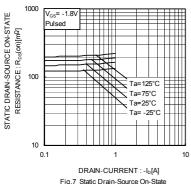
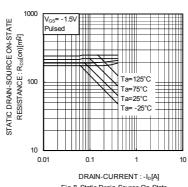


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current( I )

Fig.5 Static Drain-Source On-State Resistance vs. Drain Current( II )

Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)





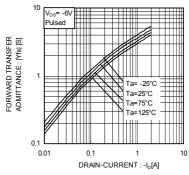
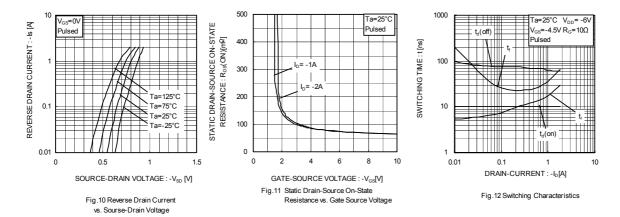


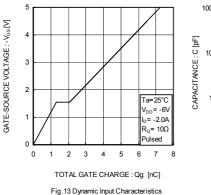
Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

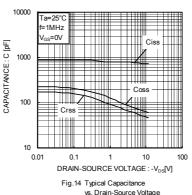
Fig.8 Static Drain-Source On-State Resistance vs. Drain Current( V )

Fig.9 Forward Transfer Admittance vs. Drain Current

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#### Measurement circuit

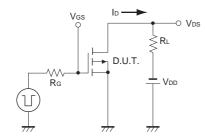


Fig.1-1 Switching Time Measurement Circuit

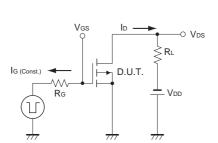


Fig.2-1 Gate Charge Measurement Circuit

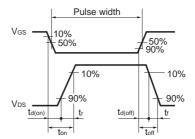


Fig.1-2 Switching Waveforms

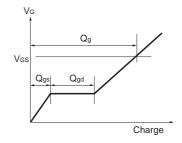


Fig.2-2 Gate Charge Waveform

#### ●Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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